

## SEMITOP<sup>®</sup>4

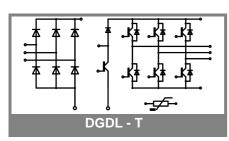
### 3-phase bridge rectifier + brake chopper + 3-phase bridge inverter sk 25 DGDL 12T4 T

Target Data

#### Features

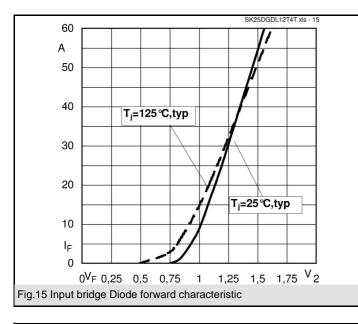
- One screw mounting module
- Fully compatible with SEMITOP<sup>®</sup>1,2,3
- Improved thermal performances by aluminium oxide substrate
- Trench4 IGBT technology
- CAL4 technology free-wheeling diode
- Integrated NTC temperature sensor

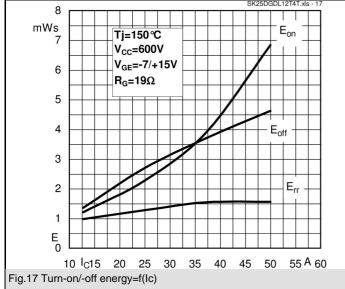
1)	V <sub>CE,sat</sub> ,	V <sub>F</sub> =	chip	level	value
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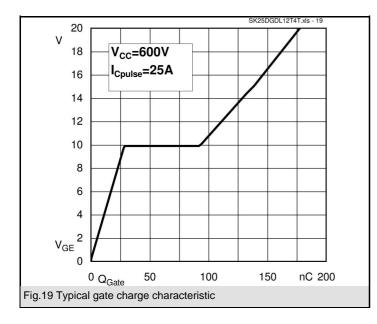


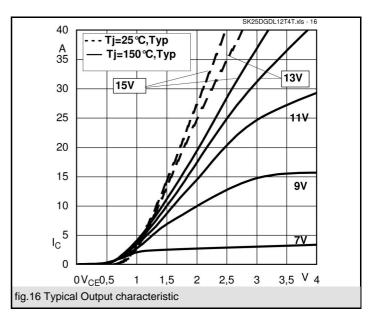
Absolute Maximum Ratings		Ts = 25 °C, unless otherwise s	Ts = 25 °C, unless otherwise specified					
Symbol Conditions		Values	Units					
IGBT - Inverter, Chopper								
V <sub>CES</sub>		1200	V					
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	45 (36)	А					
I <sub>CRM</sub>	$I_{CRM}$ = 3 x $I_{Cnom}$ , $t_p$ = 1 ms	75	Α					
V <sub>GES</sub>		± 20	V					
Т <sub>ј</sub>		-40 +175	°C					
Diode - In	verter,Chopper	·						
I <sub>F</sub>	T <sub>s</sub> = 25 (70) °C	30 (24)	Α					
I <sub>FRM</sub>	$I_{FRM} = 2xI_{Fnom}, t_p = 1 \text{ ms}$	75	Α					
Тj		-40 +150	°C					
Rectifier								
V <sub>RRM</sub>		1600	V					
I <sub>F</sub>	T <sub>s</sub> = 70 °C	46	Α					
I <sub>FSM</sub> / I <sub>TSM</sub>	t <sub>p</sub> = 10 ms , sin 180 ° ,T <sub>i</sub> = 25 °C	370	Α					
l <sup>2</sup> t	t <sub>p</sub> = 10 ms , sin 180 ° ,T <sub>i</sub> = 25 °C	684	A²s					
Tj		-40 +175	°C					
T <sub>sol</sub>	Terminals, 10 s	260	°C					
T <sub>stg</sub>		-40 +125	°C					
V <sub>isol</sub>	AC, 1 min. / 1 s	2500 / 3000	V					
	•		·					
Characteristics Ts = 25 °C, unless otherwise specified								
Symbol	Conditions	min. typ. max.	Units					

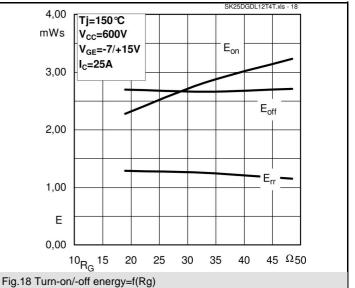
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Inverter								
V <sub>CEsat</sub>	I <sub>C</sub> = 25 A, T <sub>i</sub> = 25 (150) °C		1,85 (2,25)	2,05 (2,45)	V			
V <sub>GE(th)</sub>	$V_{GE} = V_{CE}, I_C = 1 \text{ mA}$	5	5,8	6,5	V			
V <sub>CE(TO)</sub>	T <sub>j</sub> = 25 °C (150) °C		1,1 (1)	1,3 (1,2)	V			
r <sub>T</sub>	T <sub>j</sub> = 25 °C (150) °C		30 (50)		mΩ			
C <sub>ies</sub>	$V_{CE} = 25 V_{GE} = 0 V, f = 1 MHz$		1,43		nF			
C <sub>oes</sub>	$V_{CE} = 25 V_{GE} = 0 V, f = 1 MHz$		0,11		nF			
C <sub>res</sub>	V <sub>CE</sub> = 25 V <sub>GE</sub> = 0 V, f = 1 MHz		0,085		nF			
R <sub>th(j-s)</sub>	per IGBT		0,96		K/W			
t <sub>d(on)</sub>	under following conditions		22		ns			
t <sub>r</sub>	$V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V}$		19,5		ns			
t <sub>d(off)</sub>	$I_{\rm C} = 25 \text{ A}, T_{\rm j} = 150 \text{ °C}$		288		ns			
t <sub>f</sub>	$R_{Gon} = R_{Goff} = 19 \Omega$		77,5		ns			
E <sub>on</sub>	inductive load		2,27		mJ			
E <sub>off</sub>			2,7		mJ			
	verter,Chopper							
$V_F = V_{EC}$	I <sub>F</sub> = 25 A, T <sub>j</sub> = 25(150) °C		2,4 (2,45)	2,75 (2,8)	V			
V <sub>(TO)</sub>	T <sub>j</sub> = 25 °C (150) °C		1,3 (0,9)		V			
r <sub>T</sub>	T <sub>j</sub> = 25 °C (150) °C		44 (62)	50 (68)	mΩ			
R <sub>th(j-s)</sub>	per diode		1,7		K/W			
I <sub>RRM</sub>	under following conditions		-		А			
Q <sub>rr</sub>	$I_F = A, V_R = V$		-		μC			
E <sub>rr</sub>	V <sub>GE</sub> = 0 V, T <sub>j</sub> = 150 °C				mJ			
	di <sub>F</sub> /dt = - A/µs							
Diode - R	ectifier							
V <sub>F</sub>	I <sub>F</sub> = 25 A, T <sub>i</sub> = 25() °C		1,1		V			
V <sub>(TO)</sub>	T <sub>i</sub> = 150 °C		0,8		V			
r <sub>T</sub>	T <sub>j</sub> = 150 °C		13		mΩ			
R <sub>th(j-s)</sub>	per diode		1,25		K/W			
Temperat	ur sensor							
R <sub>ts</sub>	5 %, T <sub>r</sub> = 25 (100 ) °C		5000(493)		Ω			
Mechanical data								
W			60		g			
M <sub>s</sub>	Mounting torque		3,5		Nm			

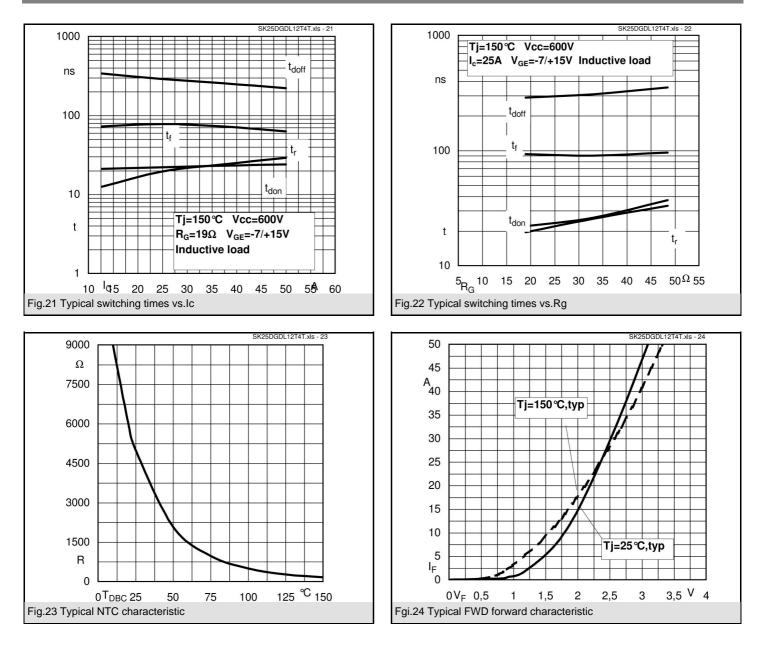




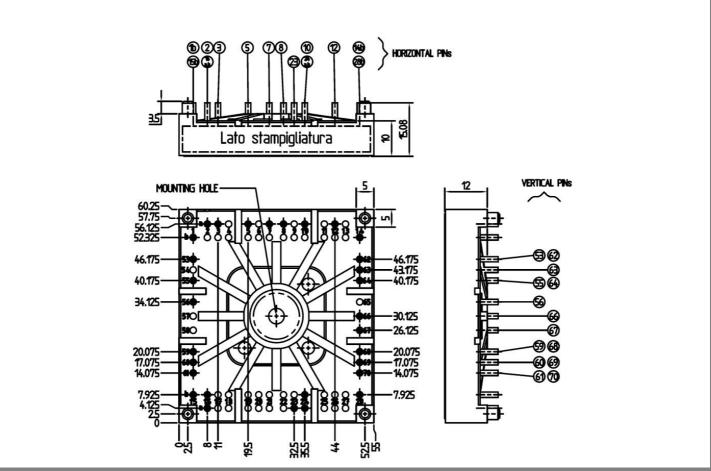


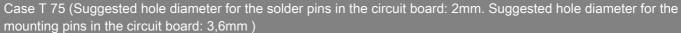


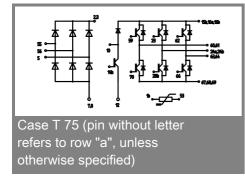




Dimensions in mm







This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

\* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.